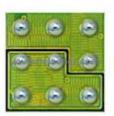




EPC2106ENGRT Information



For Reference Only

Part Number EPC2106ENGRT

Manufacturer EPC

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Arrays

Description TRANS GAN 2N-CH 100V BUMPED DIE

Package Die

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









EPC2106ENGRT Specifications

	Report errors?
Supplier Device Package	Die
Package / Case	Die
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 150°C (TJ)
Power - Max	-
Input Capacitance (Ciss) (Max) @ Vds	75pF @ 50V
Gate Charge (Qg) (Max) @ Vgs	0.73nC @ 5V
Vgs(th) (Max) @ Id	2.5V @ 600μA
Rds On (Max) @ Id, Vgs	70 mOhm @ 2A, 5V
Current - Continuous Drain (Id) @ 25°C	1.7A
Drain to Source Voltage (Vdss)	100V
FET Feature	GaNFET (Gallium Nitride)
FET Type	2 N-Channel (Half Bridge)
Series	eGaN?
Package	Die
	Transistors - FETs, MOSFETs - Arrays
Category	Discrete Semiconductor Products
Manufacturer	EPC
Manufacturer Part Number	EPC2106ENGRT

EPC2106ENGRT Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

EPC2106ENGRT Payment Methods



















EPC2106ENGRT Shipping Methods













If you have any question about EPC2106ENGRT, please do not hesitate to contact us!

Website: https://www.heisener.com E-mail: salesdept@heisener.com